

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

3. Applications

- High-side load switch
- Battery management
- DC-to-DC conversion
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-17.1	А
Static chara	cteristics		·				
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -10.6 A; T _j = 25 °C		-	8.4	10	mΩ
		V _{GS} = -2.5 V; I _D = -8.6 A; T _j = 25 °C		-	12	16	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	S	source	1 2 3 4					
2	S	source	_فـفـفــف_	P				
3	S	source						
4	G	gate						
5	D	drain						
6	D	drain	للممما	S 017aaa257				
7	D	drain	8 7 6 5 MI DAK22 (SOT9002 1)					
8	D	drain	MLPAK33 (SOT8002-1)					

6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
PXP010-20QX	MLPAK33	plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PXP010-20QX	8AF

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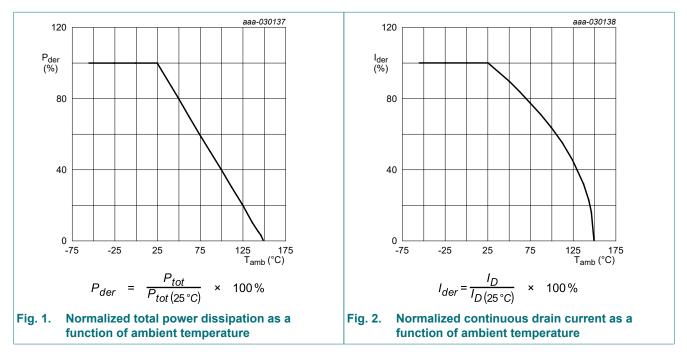
8. Limiting values

Table 5. Limiting values

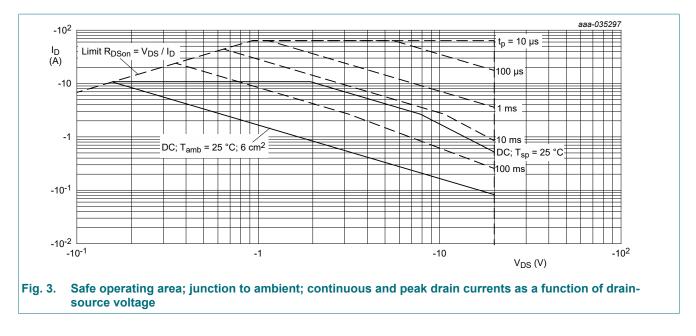
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-17.1	А
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-10.8	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-6.7	А
		V _{GS} = -4.5 V; T _{sp} = 25 °C		-	-37.6	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-63	А
P _{tot}	total power dissipation	T _{amb} = 25 °C; t ≤ 5 s	[1]	-	4.3	W
		T _{amb} = 25 °C	[1]	-	1.7	W
		T _{sp} = 25 °C		-	21	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.7	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



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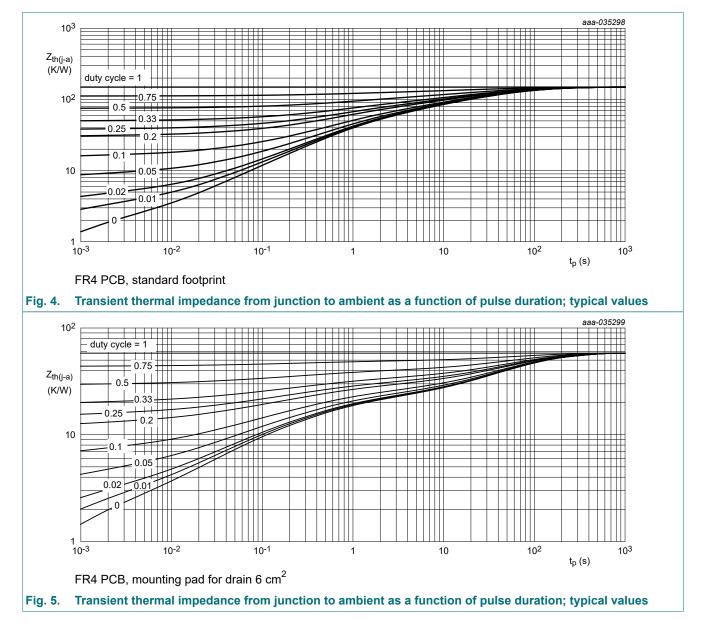
PXP010-20QX

9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	150	190	K/W
			[2]	-	60	75	K/W
		in free air; t ≤ 5 s	[2]	-	23	29	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	4	6	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

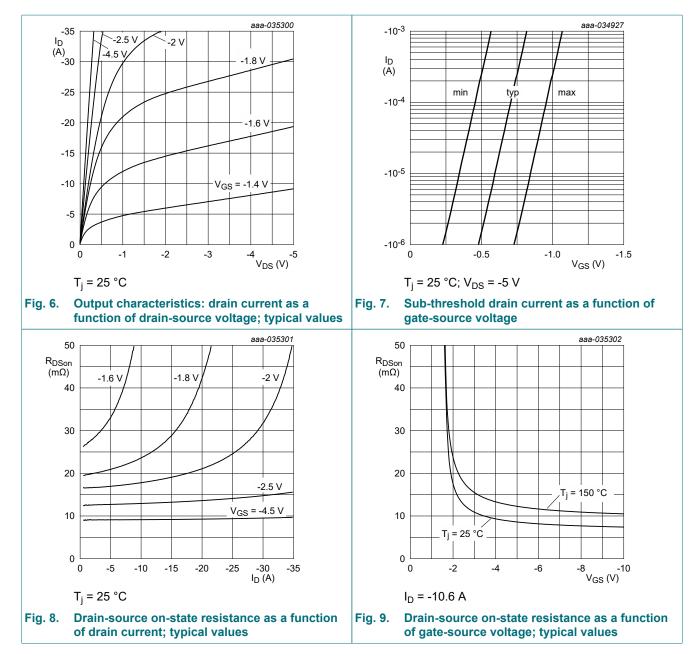
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



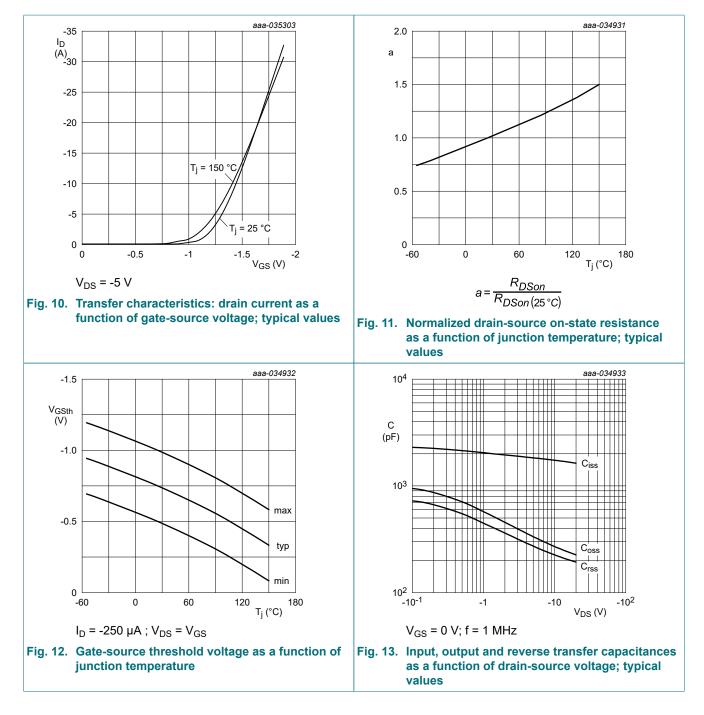
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = -250 μA; V _{DS} =V _{GS} ; T _j = 25 °C	-0.5	-0.75	-1	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V _{GS} = -4.5 V; I _D = -10.6 A; T _j = 25 °C	-	8.4	10	mΩ
	resistance	V _{GS} = -4.5 V; I _D = -10.6 A; T _j = 150 °C	-	12.3	14.7	mΩ
		V _{GS} = -2.5 V; I _D = -8.6 A; T _j = 25 °C	-	12	16	mΩ
		V _{GS} = -1.8 V; I _D = -0.5 A; T _j = 25 °C	-	20	31	mΩ
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -10.6 A; T _j = 25 °C	-	35	-	S
R _G	gate resistance	f = 1 MHz	-	17	-	Ω
Dynamic ch	aracteristics	· · ·	I			
Q _{G(tot)}	total gate charge	V _{DS} = -10 V; I _D = -10.6 A; V _{GS} = -4.5 V;	-	19.5	29	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.7	-	nC
Q _{GS(th)}	pre-threshold gate- source charge		-	1.35	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	1.35	-	nC
Q _{GD}	gate-drain charge		-	5.2	-	nC
V _{GSpl}	gate-source plateau voltage	V _{DS} = -10 V; I _D = -10.6 A; T _j = 25 °C	-	1.5	-	V
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	1730	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	270	-	pF
C _{rss}	reverse transfer capacitance		-	230	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -8.6 A; V _{GS} = -4.5 V;	-	3	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	13	-	ns
t _{d(off)}	turn-off delay time	1	-	131	-	ns
t _f	fall time	1	-	80	-	ns
Source-drai	n diode	· ·				
V _{SD}	source-drain voltage	I _S = -1.7 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.7	-1.2	V
t _{rr}	reverse recovery time	I _S = -1.7 A; dI _S /dt = 100 A/μs;	-	105	-	ns
Q _r	recovered charge	V _{GS} = -4.5 V; V _{DS} = -10 V; T _j = 25 °C	-	115	-	nC
t _a	reverse recovery rise time	1	-	52	-	ns
t _b	reverse recovery fall time	1	-	53	-	ns

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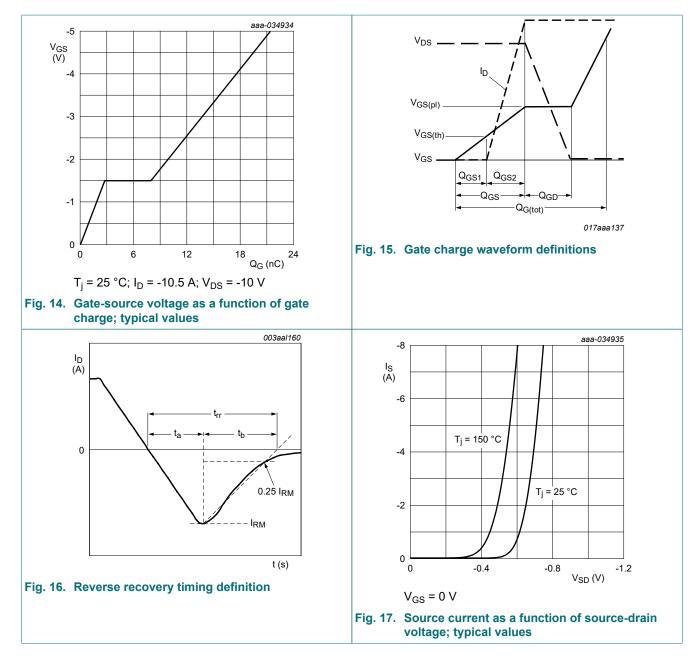


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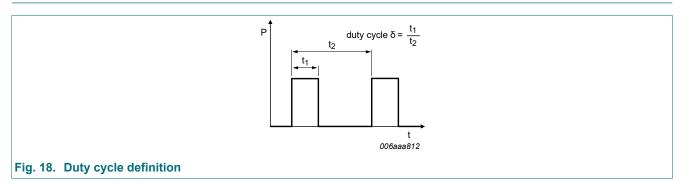


8 / 14

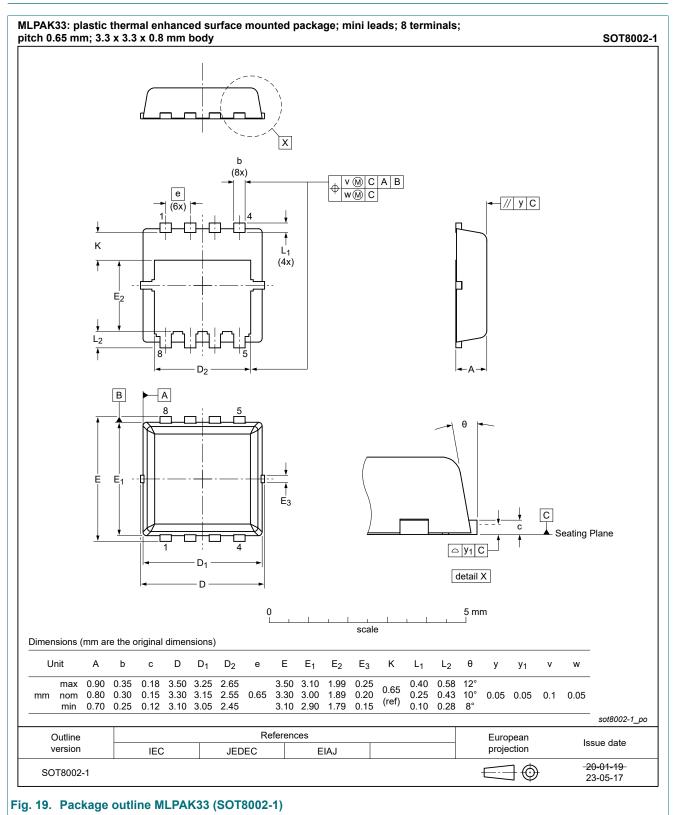
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11. Test information

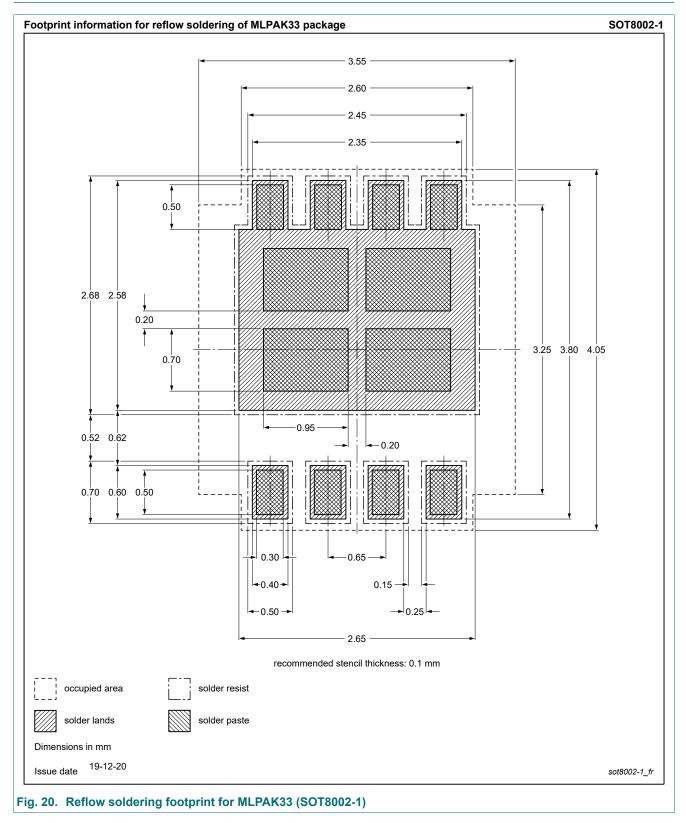


12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PXP010-20QX v.2	20230731	Product data sheet	-	PXP010-20QX v.1			
Modifications:	Chapter "Package or	utline": drawing update					
PXP010-20QX v.1	20221031	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	5
10.	Characteristics	6
11.	Test information	9
12.	. Package outline	10
	Soldering	
14.	. Revision history	12
	Legal information	
	-	

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